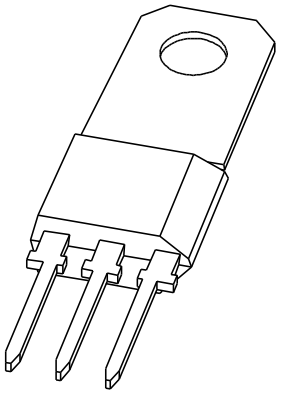
DATA SHEET



BF583; BF585; BF587
NPN high-voltage transistors

Product specification
Supersedes data of September 1994
File under Discrete Semiconductors, SC04

1996 Dec 09

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NPN high-voltage transistors BF583; BF585; BF587

FEATURES

- Low feedback capacitance.

APPLICATIONS

- For use in video output stages of black and white and colour television receivers.

DESCRIPTION

NPN transistors in a TO-202 plastic package.

PINNING

PIN	DESCRIPTION
1	emitter
2	collector
3	base

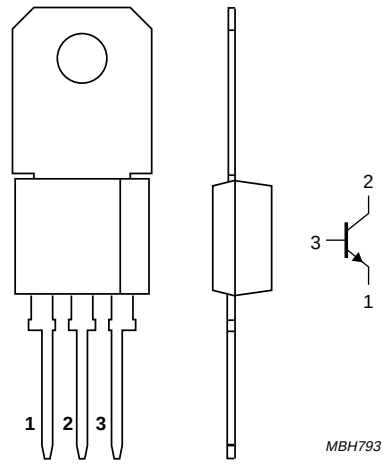


Fig.1 Simplified outline (TO-202) and symbol.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter			
	BF583		–	300	V
	BF585		–	350	V
	BF587		–	400	V
V_{CEO}	collector-emitter voltage	open base			
	BF583		–	250	V
	BF585		–	300	V
	BF587		–	350	V
I_{CM}	peak collector current		–	100	mA
P_{tot}	total power dissipation	in free air; $T_{amb} \leq 25$ °C	–	1.6	W
h_{FE}	DC current gain	I_C = 25 mA; V_{CE} = 20 V	–	50	
C_{re}	feedback capacitance	$I_C = i_c = 0$; V_{CE} = 30 V; f = 1 MHz	–	1.8	pF
f_T	transition frequency	I_C = 10 mA; V_{CE} = 10 V	70	110	MHz

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter			
	BF583		–	300	V
	BF585		–	350	V
	BF587		–	400	V
V_{CEO}	collector-emitter voltage	open base			
	BF583		–	250	V
	BF585		–	300	V
	BF587		–	350	V
V_{EBO}	emitter-base voltage	open collector	–	5	V
I_C	collector current (DC)		50	–	mA
I_{CM}	peak collector current		–	100	mA
I_{BM}	peak base current		–	50	mA
P_{tot}	total power dissipation	in free air; $T_{amb} \leq 25$ °C	–	1.6	W
		in free air; $T_{mb} \leq 25$ °C	–	5	W
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

THERMAL CHARACTERISTICS

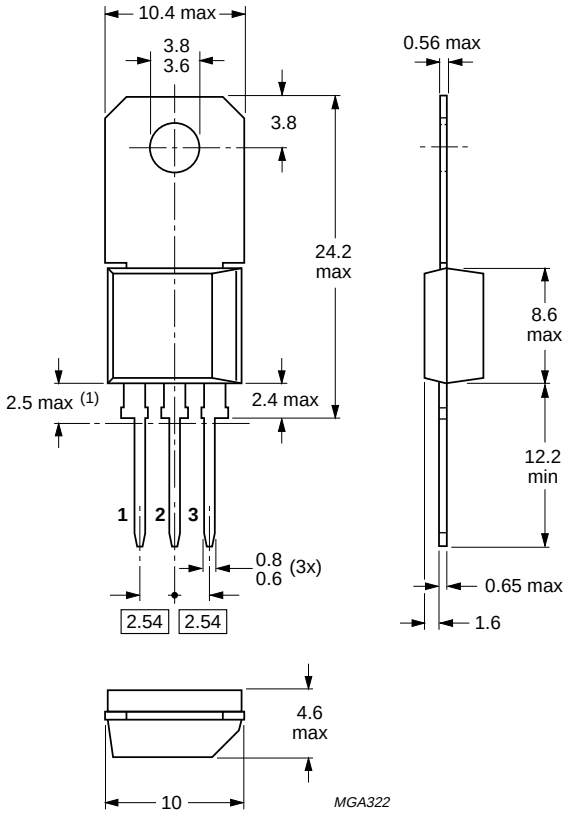
SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	78	K/W
$R_{th\ j\text{-}mb}$	thermal resistance from junction to mounting base	25	K/W

CHARACTERISTICS

$T_j = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0$; $V_{CB} = 300$ V	–	20	nA
		$I_E = 0$; $V_{CB} = 250$ V; $T_j = 150$ °C	–	20	µA
I_{EBO}	emitter cut-off current	$I_C = 0$; $V_{EB} = 5$ V	–	100	nA
h_{FE}	DC current gain	$I_C = 25$ mA; $V_{CE} = 20$ V	50	–	
		$I_C = 40$ mA; $V_{CE} = 20$ V	20	–	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 30$ mA; $I_B = 5$ mA	–	600	mV
C_c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = 30$ V; f = 1 MHz	–	2.5	pF
C_{re}	feedback capacitance	$I_C = i_c = 0$; $V_{CE} = 30$ V; f = 1 MHz	–	1.8	pF
f_T	transition frequency	$I_C = 10$ mA; $V_{CE} = 10$ V	70	110	MHz

PACKAGE OUTLINE



Dimensions in mm.

(1) Terminal dimensions within this zone are uncontrolled.

Fig.2 TO-202.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

NOTES

NOTES

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